

Analytical Model for Atomic Relaxation in Twisted Moiré Materials

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By virtue of being atomically thin, the electronic properties of heterostructures built from two-dimensional materials are strongly influenced by atomic relaxation where the atomic layers should be thought of as membranes rather than rigid 2D crystals. We develop an analytical treatment of lattice relaxation for twisted 2D moiré materials obtaining semi-analytical results for lattice displacements, real and momentum space moiré potentials, pseudomagnetic fields and electronic band structures. We benchmark our results for twisted bilayer graphene and twisted homobilayers of tungsten diselenide using large-scale molecular dynamics simulations finding that our theory is valid for magic angle twisted bilayer graphene (angles $\gtrsim 1^\circ$), and for twisted TMDs for twist angles $\gtrsim 7$ degrees.

Introduction— Ever since the seminal paper by dos Santos, Peres and Castro Neto [1], the community has been fascinated by the modification of the electronic properties of two-dimensional (2D) materials using twist angle [2, 3]. Twisted 2D materials have observable moiré patterns that depend on twist angle [4, 5], lattice symmetry [6, 7], and lattice mismatch [8]. These moiré potentials in turn strongly modify the electronic properties in ways that can be observed in STM [5, 9], transport [8, 10–13], and ARPES [14–17].

Following the experimental observation of these flat bands by Jarillo-Herrero and co-workers in 2018 [18], the field experienced a surge of exploration and discovery. Notably, significant advancements were made in understanding various twisted layered structures. These developments include, but are not limited to, investigations into twisted double bilayer graphene [19, 20], twisted mono-bilayer graphene [21–23], and twisted trilayers and multilayers [24–27], each revealing unique electronic properties. This was further extended to twisted thin films [28–30] with tunable electronic characteristics and to transition metal dichalcogenides (TMDs) [31–34] and even twisted cuprate superconductors [35]. These rich and diverse developments collectively contribute to our evolving understanding of electronic phenomena in twisted moiré materials.

One wrinkle in this story is that 2D atomic layers are not rigid lattices, but flexible electronic membranes. This was well-known in early experimental studies (see e.g. [36, 37]). Theoretical treatments considering the electronic and mechanical properties on equal footing soon followed [38–40]. At small twist angles, small displacements from the rigid atomic lattice configuration with a corresponding small cost in elastic energy can give large gains in the electronic potential energy. Since lattice relaxation effects are expected to strongly modify the electronic structure for twisted bilayer graphene at magic angle, the original claims of flat bands was met with some

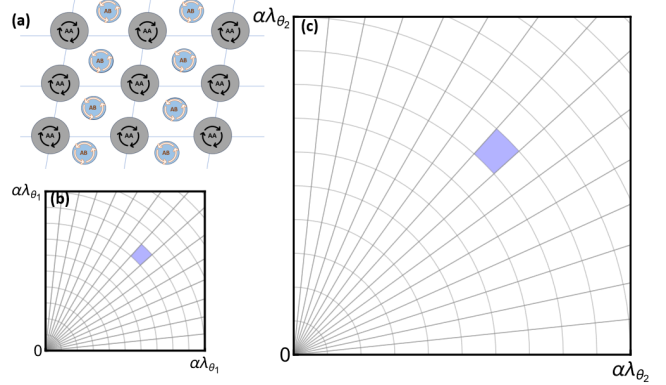


FIG. 1. Cartoon illustrating assumptions for our analytical model of lattice relaxation in twisted bilayer graphene. (a) Lattice relaxation prompts the neighborhoods around the energetically favorable AB-like and BA-like domains to counter-rotate against external twisting, aiming to restore the global minimum stacking in bilayer graphene. Simultaneously, the emergent structure’s periodicity induces AA-like domains to rotate in the same direction as the external twist. The overall domain-like rotational nature is dictated by the constraint $\nabla \cdot D(r) = 0$, where $D(r)$ is the displacement field due to lattice relaxation. (b, c) Equivalent local AA regions in two different twist angle configurations. The shaded regions are geometrically mapped to each other, with boundary locations scaling with the moiré period ($\sim 1/\sin(\theta/2)$) and enclosed area scaling with the period square ($\sim 1/\sin^2(\theta/2)$).

skepticism. It was only after the experimental observations that relaxation effects were considered in magic angle twisted bilayer graphene [41]. As expected, relaxation effects strongly modify the electronic structure. Remarkably, and for reasons that are not fully understood prior to this work, relaxation actually further flattens and isolates the lowest energy moiré bands [41–43] confirming that atomic relaxation is an important ingredient to un-

derstand the superconductivity and correlated insulator states observed in twisted bilayer graphene.

The importance of lattice reconstruction is determined by the interplay between the van der Waals energy and elastic energy. Nam and Koshino [41] identified the dimensionless quantity $\sqrt{V_0}/(\lambda + \mu)/\sin(\theta/2)$ to capture when lattice relaxation effects are important. Here V_0 is the van der Waals energy, μ and λ are Lamé elastic coefficients. Using accepted values [44, 45], we estimate that relaxation effects will be an order-of-magnitude stronger in twisted TMDs compared to TBG; since lattice relaxation effects are expected to be important for $\theta \lesssim 1$ degree in TBGs, we anticipate it to be important at even larger angles for twisted TMDs.

More generally, since moiré systems now serve as experimental arenas showcasing a plethora of emergent and exotic phenomena, as well as possible quantum simulators [31, 46], an accurate understanding of lattice relaxation effects is essential. To date, studies on atomic relaxation have been relied on elasticity theory [38, 41], DFT-parametrized effective models [42], or large-scale classical atomic molecular dynamics calculations [43]. However, these methods typically involve computationally intensive procedures, restricting accessibility and potentially obscuring the underlying physics.

In this work we propose a fully analytical and physically motivated theory for atomic relaxation. By benchmarking our results with both LAMMPS (involving numerical calculations with more than 4 million atoms) and tight-binding calculations, we show that our theory is valid for a wide range of twist angles for both twisted graphene and TMDs, including for magic angle twisted bilayer graphene. This enables us to propose an effective electronic model for twisted bilayer graphene that fully captures the effects of lattice relaxation on observables including band width, Fermi velocity and pseudo-magnetic fields. We note that beyond agreement with numerical benchmarks, the success of the original rigid model [1, 47] was largely due to its conceptual clarity and computational simplicity. By providing a simple analytic extension to this model to account for atomic relaxation, we provide an equally simple and broadly accessible way to incorporate the effects of lattice relaxation effects in the study of twisted 2D materials that we have shown are generally important in regimes where exotic strongly correlated phenomena have been observed in these materials.

Analytical Model— We begin by considering twisted bilayer graphene (TBG) and extend it later to other twisted homobilayers. The geometry of twisted graphene with non-interacting atoms is constructed from a fixed stacking (say AA-stacking) and then rotating one layer relative to the other until a new commensurate unit cell is formed. This is called the rigid atomic configuration of TBG. However, the atoms interact with each other through the competition between in-plane elastic interaction and out-of-plane van der Waals interactions. The 2D sheets are more like elastic membranes that gain elec-

tronic energy by expanding the energetically favourable AB-like regions at the expense of elastic energy. This modification of the rigid atomic positions due to lattice relaxation is called the displacement field $D(r)$. Since the rigid distribution of atoms in TBG is smooth and fully described analytically [50], it is expected that $D(r)$ is also smooth and can be described analytically. To leading order, it should sufficiently be described by the first Fourier harmonics of the moiré triangular lattice

$$D(r) = \sum_{\{g\}} \alpha(g) e^{ig \cdot r} \quad (1)$$

where $\{g\} = \vec{g}_1, \dots, \vec{g}_6$ is the set of moiré reciprocal lattice vectors with minimum non-trivial magnitude and $\alpha(\{g\})$ are 2D vector expansion coefficients that we determine below.

Our key insight is illustrated in Fig. 1. When the two sheets are not rotated, they are in a low-energy state. After rotation, various possible stackings exist. However, there are points with special registry, the information of which can be used to construct our proposed analytical model. AB and BA points are global energy minima, while AA points are global energy maxima [51]. Around these three special points, the external twist angle will cause the neighborhood of these points to rotate, altering the energy configuration; atoms around AB and BA points will rotate in the opposite direction to the external twisting (to restore the low-energy configuration), while atoms around the AA point will rotate in the same direction as the external twist (to move away from the maximum energy configuration). This observation is supported by the dominance of the AB and BA region in low-angle twist bilayer graphene [52]. In our model, these properties are imposed by requiring that the relaxation field is incompressible:

$$\nabla \cdot D(r) = 0. \quad (2)$$

In addition, by symmetry we add additional constraints on $\alpha(\{g\})$ requiring that $\alpha(-g) = \alpha^*(g)$, and $\alpha(R[2\pi/3]g) = R[2\pi/3]\alpha(g)$ (where $R[\phi]$ is a 2D rotational matrix by angle ϕ). After some algebra (see Supplemental Material), we find

$$D(r) = \alpha_1 \sin(g_1 \cdot r) + R[2\pi/3] \alpha_1 \sin(g_2 \cdot r) + R[4\pi/3] \alpha_1 \sin((g_1 + g_2) \cdot r). \quad (3)$$

Here $\alpha_1 = C\{-\sin(\pi/6), \cos(\pi/4)\}$, where C is a scale-factor. This is the main result of our paper. It provides a fully analytic expression for $D(r)$ that contains only a single unknown parameter C determined either from numerical calculations (as we do below) or from experiment.

We now glean further insights from this theory. We first observe that the geometry of different moiré unit cells corresponding to different twist angles can be uniquely mapped to each other as illustrated in Fig. 1. One point in a given unit cell ($\eta \sin(\theta_1/2)\lambda_{\theta_1}$) is equivalent to another point in another unit cell ($\eta \sin(\theta_2/2)\lambda_{\theta_2}$) where

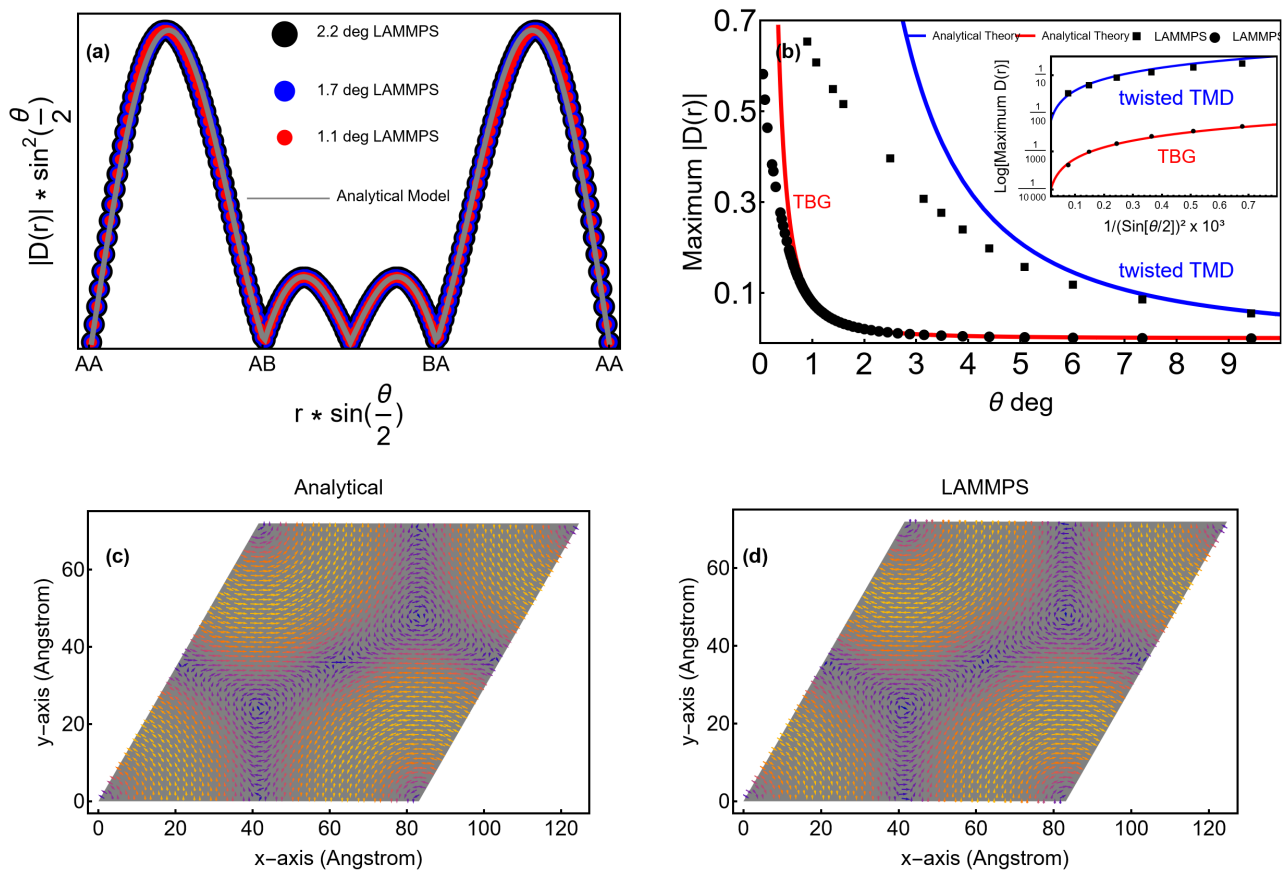


FIG. 2. Validation of the analytical model within and across different twist angles. (a) Linear cuts of the magnitude of the displacement field along the diagonal line of panels (c and d) starting from the origin. Colored dots represent data for different twist angles. The (x-axis) is scaled by units of moiré period with the maximum displacement is scaled by units of moiré area. The gray continuous line represents the analytical model. Both LAMMPS data for different twist angles and the analytical model collapse to the same curve. Different twist angles are represented by dots of different sizes to prevent complete overlap. (b) Maximum value of the displacement field (in units of angstrom) as a function of angle, comparing LAMMPS with the predictions of the analytical model for both twisted bilayer graphene and twisted bilayer WSe_2 . (c) In-plane displacement field of TBG Layer 1, as calculated using the analytical model proposed in this work, for a twist angle of 1.69 degrees. (d) The corresponding in-plane displacement field of Layer 1 as computed by molecular dynamics using LAMMPS.

λ_{θ_1} and λ_{θ_2} are the moiré periods for θ_1 and θ_2 and η is any real fraction between 0 and 1. The two points are equivalent because both have moved by the same angular distance ($dr = r d\theta$) and therefore have identical local stacking environments. We conclude that all lengths in the problem scale as $1/\sin(\theta/2)$.

We note that the two mapped areas have different numbers of atoms proportional to the shaded area in Fig. 1b,c. If we further assume that the van der Waals force varies smoothly at the atomic scale, this implies that the force scales with the area of the unit cell or as $1/\sin^2(\theta/2)$. This immediately suggests the following scaling rule for the analytical theory. If we define $r' = r \sin(\theta/2)$, then

$$\begin{aligned} D(r') \sin^2\left(\frac{\theta}{2}\right) &= \alpha_1 \sin(G_1 \cdot r') + R [2\pi/3] \alpha_1 \sin(G_2 \cdot r') + \\ &\quad R [4\pi/3] \alpha_1 \sin((G_1 + G_2) \cdot r') \\ &\approx \text{const}, \end{aligned}$$

where we have used $g_i = G_i \sin(\theta/2)$. The profile of the right-hand side is independent of the twist angle θ implying that the magnitude of the displacement field normalized by the moiré cell area is the same for different twist angles. This allows us to write $C = \alpha/(\sin^2(\theta/2))$. Therefore, the magnitude of the displacement field, normalized by moiré cell area plotted as a function of linear paths normalized by the moiré length should be independent of twist angle. We test this collapse using LAMMPS molecular dynamics numerical simulations (discussed below). Figure 2a shows LAMMPS results for three differ-

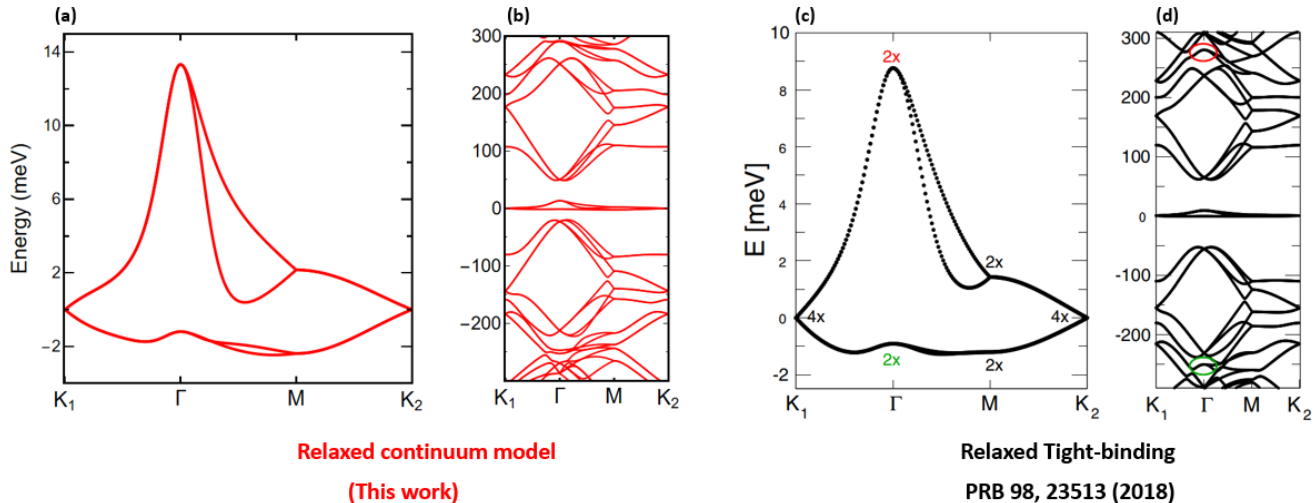


FIG. 3. Validating the effective relaxed continuum model with relaxed tight-binding calculations. (a) Low-energy bands of the proposed relaxed continuum model for $\theta = 1.08^\circ$. (b) Zoom-out view of the band structure of the effective model showing additional bands around charge neutrality points. (c, d) Corresponding tight-binding results to (a) and (b) taken from [48]. It is evident that the effective continuum model captures not only the low-energy bands but also the high-energy features of the spectrum. Similar agreement is achieved in comparison with the results of [49] (not shown here).

ent twist angles plotting $\sin^2(\theta/2)|D(r)|$ as a function of $r' = \sin(\theta/2)r$ for a line cut through the moiré unit cell (see Fig. 2c) starting at the origin and moving diagonally across the unit cell. Beyond the collapse of the numerical data, we also find excellent agreement between our analytical model (grey line) and the molecular dynamics simulations. The next step is to use the LAMMPS data to fix α , the single parameter of the theory. The fits are done at large angle where the theory is expected to work well (see inset to Fig. 2b). We find that $\alpha_{\text{TBG}} = 3.7 \times 10^{-4}$ and $\alpha_{\text{TTMD}} = 2.3 \times 10^{-2}$ for twisted graphene bilayers and twisted homobilayers of WSe₂ respectively; as anticipated $\alpha_{\text{TTMD}} \gg \alpha_{\text{TBG}}$. We attribute this to both the larger Lamé coefficients and smaller interlayer potential in TBG compared to twisted TMDs. Remarkably, for twisted bilayer graphene we find that the theory presented here works even for magic angle, and is valid for $\theta \gtrsim 1^\circ$. While for twisted TMDs we find that the relaxation effects are more important (larger displacement fields for the same twist angle) and the theory is valid for $\theta \gtrsim 7^\circ$. Having fixed the parameter α with LAMMPS, we can now compare the full $D(r)$ between theory and simulations. This is shown for $\theta = 1.69^\circ$ in Fig. 2c,d where the displacement fields are almost identical. For very small twist angles, the analytical model starts to deviate from the LAMMPS simulations. We attribute this to the breakdown of our assumption for a constant elastic energy within the unit cell. However, we expect Eq. 3 that is based on symmetry to remain valid with a modified scaling function for α_1 . We will explore lattice relaxation in this very low angle regime in a subsequent

paper [53].

Moiré potential profiles— Armed with the analytical theory for $D(r)$, we can now incorporate relaxation into the continuum model. The continuum model [1, 47] is now well established in the literature. In this framework, the Bloch states $\psi(k)$ are expressed as a linear combination of monolayer graphene plane waves ϕ_i , given by $\psi(k) = \sum_i \alpha_i \phi_i$. The set of plane waves ϕ_i is determined by the geometry of the emergent moiré potential and the matrix elements of the moiré Hamiltonian $\langle \phi_m | H | \phi_n \rangle$, based on the interlayer coupling strength. The moiré potential is approximately periodic, and therefore, it is expanded in terms of the harmonics of the emergent lattice $V(r) = \sum_g \beta(g) e^{ig \cdot r}$. The moiré potential profiles will be modified by the inclusion of atomic relaxation. In the Supplemental Material, we show in Fig. S1 the moiré potential profiles in both real and reciprocal lattices for both the rigid and relaxed configurations. We observe that for the rigid case, the moiré potential for different sublattice-sublattice tunnelings are related by a translation. Lattice relaxation breaks this symmetry and energetically favorable configurations in the relaxed lattice have stronger moiré potentials. This asymmetry encodes the information about the role of atomic relaxation on the electronic properties. The effect of the moiré potential varies as a function of twist angle. As the twist angle decreases, the moiré unit cells exhibit a more textured pattern, necessitating the inclusion of more matrix elements to capture the low-energy spectrum. This is illustrated in Fig. S2 of the Supplemental Material where we compute the strength of the matrix elements

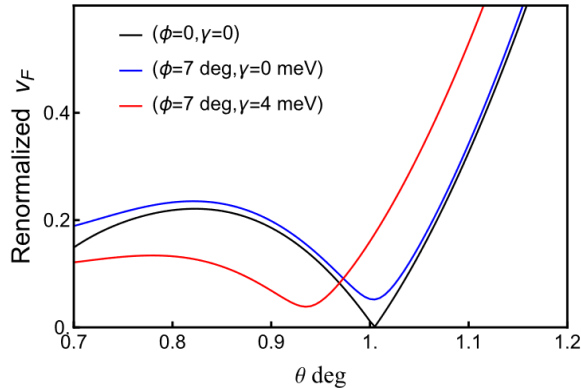


FIG. 4. Relaxation-induced Fermi velocity renormalization in twisted bilayer graphene. The black curve illustrates the standard continuum model with $w_1 \neq w_2$. The blue curve represents the modification to the Fermi velocity, incorporating the relaxation parameter ϕ in Eq. 4 within the first-shell approximation. This modification results in a non-vanishing value of the Fermi velocity at the magic angle. The red curve also incorporates the effects of the emergent pseudomagnetic field with an intensity equivalent to 4 meV. The pseudomagnetic field shifts the value of the first magic angle.

for various twist angles. Similar to the rigid model the large twist angles can be adequately represented by keeping only the first-shell matrix elements, while for small twist angles where lattice relaxation is important, require additional moiré matrix elements. In addition, as the twist angle decreases, the reciprocal lattice vectors become shorter. This allows the same strength of matrix elements to couple more monolayer basis functions.

Effective relaxed electronic model— We focus here on magic angle twisted bilayer graphene where relaxation effects are known to be important and numerous exotic phenomena have been observed experimentally. As shown in the Supplemental Material Fig. S2, close to magic angle the first order elements are dominant. Motivated by this, we propose the following modified effective continuum model valid for $\theta \gtrsim 1^\circ$ that captures the physics of the low energy-bands. Within the usual continuum model [47, 50], the interlayer coupling term should be modified to

$$T = \begin{pmatrix} w_1 e^{i\phi} & w_2 \\ w_2 & w_1 e^{-i\phi} \end{pmatrix} + \begin{pmatrix} w_1 e^{i\phi} & w_2 e^{i2\pi/3} \\ w_2 e^{-i2\pi/3} & w_1 e^{-i\phi} \end{pmatrix} e^{ig_1 \cdot r} \\ + \begin{pmatrix} w_1 e^{i\phi} & w_2 e^{i4\pi/3} \\ w_2 e^{-i4\pi/3} & w_1 e^{-i\phi} \end{pmatrix} e^{i(g_1+g_2) \cdot r} \quad (4)$$

where w_1 and w_2 represent the same and opposite sublattice tunnelling, respectively and we introduce a new relaxation parameter ϕ that encodes information about the domain-like rotation. In the rigid case, $w_1 = w_2$ and $\phi = 0$ [1, 47]. In this case, the low-energy bands overlap

with the high-energy bands and the flat bands are not isolated. When $w_1 \neq w_2$, the isolation gap becomes bigger [41]. Figure 3 demonstrates a validation of the proposed effective relaxed continuum model against tight-binding calculations that includes atomic relaxation [48, 49]. The relaxation parameter ϕ is necessary to reproduce the relaxed tight-binding energy spectrum, and with this phase the electron-hole asymmetry is also well captured. The excellent agreement with the tight-binding calculations indicate that our proposed effective relaxed model should be used as the correct non-interacting Hamiltonian on which interacting theories could be built.

The effects of atomic relaxation become more pronounced at a small twist angle. Detailed results for small-angle twisted structures will be published elsewhere [53]. However, here, in Fig. 4 we show the Fermi velocity renormalization of our proposed relaxed continuum model. To achieve this, we also include the effect of atomic relaxation in generating a pseudo-magnetic field that couples to the monolayer graphene basis functions (see Supplementary Materials for details). We can observe that around the magic angle ~ 1 degree, the effect of the new relaxation parameter ϕ is to increase the Fermi velocity, while the pseudomagnetic field shifts the value of the magic angle. We note in passing that pseudomagnetic field could in principle be influenced by experimental sample preparation [54]. This implies that different experimental samples might have varying amounts of atomic relaxation, and as a consequence, the magic angle is more like a magic range that varies from one device to another.

Molecular Dynamics Simulations— In the context of small twist angles where the moiré structure is notably large and contains a substantial number of atoms within the supercell conducting first-principle calculations prove to be prohibitively expensive. In this regime, we calculate atomic relaxation with molecular dynamics simulations using Large-scale Atomic/Molecular Massively Parallel Simulator (LAMMPS) employing classical interatomic force field models [55]. While these molecular dynamics simulations allow for larger supercell sizes, they have inherent limitations on accuracy over the choice of interatomic potentials. It is our experience that while different interatomic potentials might give slightly different numerical values for the scaling factor α , their qualitative behavior and symmetry properties are identical. For twisted bilayer graphene we use the Drip potential for interlayer interactions and REBO potential for intralayer interactions [56–58]. For twisted TMDs we use the KC potential for interlayer interactions and SW potential for intralayer interactions [59, 60]. For this work, we perform relaxation calculations for the commensurate twist angles ranging from $\theta = 0.05^\circ$ to $\theta = 20^\circ$. The smallest twist angles correspond to on order of 4.3 million atoms. Despite the large number of atoms in the simulation cell, the geometry optimizations remain computationally tractable due to the low cost of the classical potentials.

Conclusion— We observe that the field of twisted moiré materials is rapidly expanding, and there is a need for

transparent, physically motivated models to understand and interpret the large influx of experimental data. In this work, we have proposed an analytical atomic relaxation model for twisted moiré materials, and we have benchmarked our model against large-scale molecular dynamics simulations, and our results with large-scale tight-binding simulations showing remarkable agreement. We have immediately identified several important consequences of this model including the emergence of a large pseudomagnetic field and the shift and softening of the magic angle. More experimentally relevant consequences of our model remain to be explored. The generality of our formalism implies that it could be used to study other twisted 2D materials including those such as TMDs where relaxation effects are more important than in twisted bilayer graphene.

Note added— During the preparation of this manuscript, Ceferino and Guinea submitted a pre-print [61] also with a similar analytical model for relaxed twisted bilayer and trilayer graphene. Unlike our work, they do not benchmark their results with large-scale molecular dynamics simulations and tightbinding models, and they do not generalize to other 2D materials, or explore the range of validity of the analytical model. In this work, we do not study graphene trilayers. Our conclusions for the importance of pseudomagnetic fields on the bandstructure largely overlap.

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